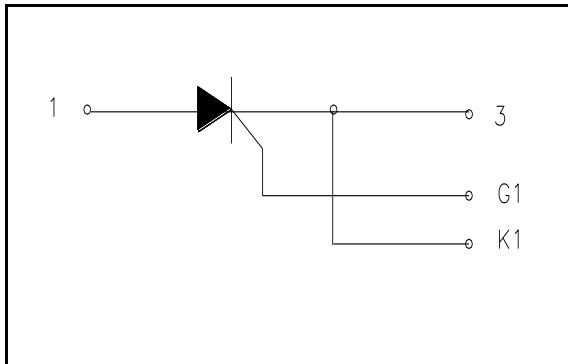


**POW-R-BLOK™**  
**Single SCR Isolated Module**  
**1000 Amperes / Up to 4000 Volts**



**Ordering Information:**

Select the complete eight-digit module part number from the table below.

Example: PS434010 is a 4000 Volt, 1000A Average Single SCR Isolated POW-R-BLOK™ Module

Type	Voltage Volts (x100)	Current Amperes (x100)
PS43	40	10

**Description:**

Powerex Single SCR Modules are designed for use in applications requiring phase control and isolated packaging. The modules are isolated for easy mounting with other components on a common heatsink.

**Features:**

- Electrically Isolated Heatsinking
- Compression Bonded Elements
- Paralleled SCRs in Module for Increased Capacity
- Metal Baseplate
- Low Thermal Impedance for Improved Current Capability

**Benefits:**

- No Additional Insulation Components Required
- Easy Installation
- No Clamping Components Required
- Reduce Engineering Time

**Applications:**

- Bridge Circuits
- AC & DC Motor Drives
- Motor Soft Starters
- Battery Supplies
- Power Supplies
- Large IGBT Circuit Front Ends

**Absolute Maximum Ratings**

Characteristics	Conditions	Symbol	Units	
Repetitive Peak Forward and Reverse Blocking Voltage		$V_{DRM}$ & $V_{RRM}$	Up to 4000	V
Non-Repetitive Peak Blocking Voltage ( $t < 5$ msec)		$V_{RSM}$	$V_{RRM} + 100V$	V
RMS Current AC Switch Configuration (180° Conduction)	180° Conduction, $T_C=47^\circ C$	$I_{T(RMS)}$	3300	A
	180° Conduction, $T_C=54^\circ C$	$I_{T(RMS)}$	3080	A
	180° Conduction, $T_C=67^\circ C$	$I_{T(RMS)}$	2640	A
(Two PS434010 in AC Switch Configuration)	<b>180° Conduction, <math>T_C=79^\circ</math></b>	$I_{T(RMS)}$	<b>2200</b>	A
RMS Current (180° Conduction)	180° Conduction, $T_C=47^\circ C$	$I_{T(RMS)}$	2355	A
	180° Conduction, $T_C=54^\circ C$	$I_{T(RMS)}$	2200	A
	180° Conduction, $T_C=67^\circ C$	$I_{T(RMS)}$	1885	A
	<b>180° Conduction, <math>T_C=79^\circ C</math></b>	$I_{T(RMS)}$	<b>1570</b>	A
Average Forward Current (180° Conduction)	180° Conduction, $T_C=47^\circ C$	$I_{T(AV)}$	1500	A
	180° Conduction, $T_C=54^\circ C$	$I_{T(AV)}$	1400	A
	180° Conduction, $T_C=67^\circ C$	$I_{T(AV)}$	1200	A
	<b>180° Conduction, <math>T_C=79^\circ C</math></b>	$I_{T(AV)}$	<b>1000</b>	A
Peak One Cycle Surge Current, Non-Repetitive $T_j = 25C, V_r = 0$	60 Hz	$I_{TSM}$	50,500	A
	50 Hz	$I_{TSM}$	42,000	A
Peak One Cycle Surge Current, Non-Repetitive $T_j = 25C, V_r = V_{rrm}$	60 Hz	$I_{TSM}$	33,600	A
	50 Hz	$I_{TSM}$	28,000	A
Peak One Cycle Surge Current, Non-Repetitive $T_j = 125C, V_r = 0$	60 Hz	$I_{TSM}$	43,500	A
	50 Hz	$I_{TSM}$	36,300	A
Peak One Cycle Surge Current, Non-Repetitive $T_j = 125C, V_r = V_{rrm}$	60 Hz	$I_{TSM}$	29,000	A
	50 Hz	$I_{TSM}$	24,200	A
Peak Three Cycle Surge Current, Non-Repetitive	60 Hz, $T_j = 125C, V_r = V_{rrm}$	$I_{TSM}$	23,000	A
Peak Three Cycle Surge Current, Non-Repetitive	60 Hz, $T_j = 125C, V_r = 0$	$I_{TSM}$	29,100	A
Peak Ten Cycle Surge Current, Non-Repetitive	60 Hz, $T_j = 125C, V_r = V_{rrm}$	$I_{TSM}$	18,000	A
Peak Ten Cycle Surge Current, Non-Repetitive	60 Hz, $T_j = 125C, V_r = 0$	$I_{TSM}$	23,000	A
$I^2t$ for Fusing for One Cycle $T_j = 125C, V_r = V_{rrm}$	8.3 milliseconds	$I^2t$	$3.5 \times 10^6$	$A^2 \text{ sec}$
	10 milliseconds	$I^2t$	$2.9 \times 10^6$	$A^2 \text{ sec}$
$I^2t$ for Fusing for One Cycle $T_j = 125C, V_r = 0$	8.3 milliseconds	$I^2t$	$8.1 \times 10^6$	$A^2 \text{ sec}$
	10 milliseconds	$I^2t$	$6.6 \times 10^6$	$A^2 \text{ sec}$
Maximum Rate-of-Rise of On-State Current, (Non-Repetitive)	Per JEDEC Standard 397 5.2.2.6	$di/dt$	600	$A/\mu s$
Maximum Rate-of-Rise of On-State Current, (Repetitive)	Per JEDEC Standard 397 5.2.2.6	$di/dt$	200	$A/\mu s$
Operating Temperature		$T_j$	-40 to +125	$^\circ C$
Storage Temperature		$T_{stg}$	-40 to +150	$^\circ C$
Max. Mounting Torque, M6 Mounting Screw			132 15	in. – Lb. Nm
Max. Mounting Torque, M10 Terminal Screw			106 12	in. – Lb. Nm
Module Weight, Typical			5.33 11.75	kg lb
V Isolation @ 25C	60 Hz, 60 sec	$V_{AC \text{ rms}}$	4000	V

Information presented is based upon manufacturers testing and projected capabilities.  
 This information is subject to change without notice.  
 The manufacturer makes no claim as to suitability for use, reliability, capability,  
 or future availability of this product.

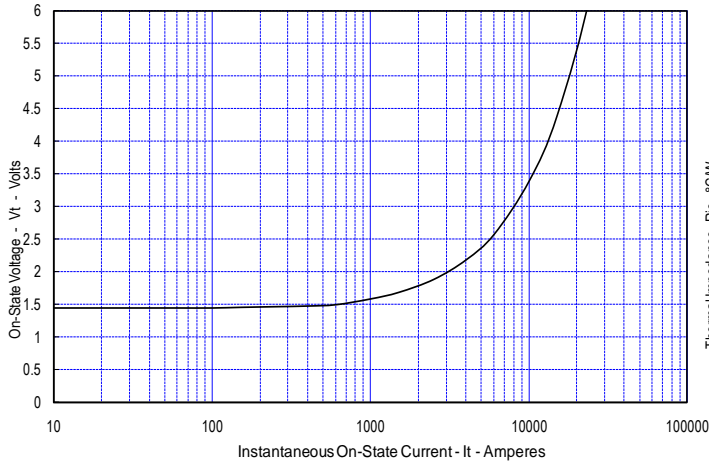
**Electrical Characteristics, T<sub>J</sub>=25°C unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Max.	Units
Repetitive Peak Forward Leakage Current	I <sub>DRM</sub>	Up to 4000V, T <sub>J</sub> =125°C		300	mA
Repetitive Peak Reverse Leakage Current	I <sub>RRM</sub>	Up to 4000V, T <sub>J</sub> =125°C		300	mA
Peak On-State Voltage	V <sub>TM</sub>	I <sub>TM</sub> =3000A, T <sub>J</sub> =25°C		2.50	V
Threshold Voltage, Low-level	V <sub>(TO)1</sub>	T <sub>J</sub> = 125°C, I = 15%I <sub>T(AV)</sub> to πI <sub>T(AV)</sub>		1.400	V
Slope Resistance, Low-level	r <sub>T1</sub>			0.193	mΩ
Threshold Voltage, High-level	V <sub>(TO)2</sub>	T <sub>J</sub> = 125°C, I = πI <sub>T(AV)</sub> to I <sub>TSM</sub>		1.391	V
Slope Resistance, High-level	r <sub>T2</sub>			0.200	mΩ
V <sub>TM</sub> Coefficients, Full Range		T <sub>J</sub> = 125°C, I = 50A to 15kA V <sub>TM</sub> = A+ B Ln I +C I + D Sqrt I	A = B = C = D =	1.610 -4.03 E-02 1.93 E-04 2.50 E-03	
Minimum dV/dt	dV/dt	Exponential to 0.80V <sub>DRM</sub> T <sub>J</sub> =125°C, Gate Open	800		V/μs
Gate Trigger Current	I <sub>GT</sub> I <sub>G</sub> Required	T <sub>J</sub> =25°C, V <sub>D</sub> =12V Min I <sub>G</sub> Required to Ensure Turn-On of Paralleled SCRs in Module	60 800mA	400	mA
Gate Trigger Voltage	V <sub>GT</sub>	T <sub>J</sub> =25°C, V <sub>D</sub> =12V		4.5	Volts
Non-Triggering Gate Voltage	V <sub>GDM</sub>	T <sub>J</sub> =125°C, V <sub>D</sub> = ½ V <sub>DRM</sub>		0.15	Volts
Holding Current	I <sub>H</sub>			600	mA
Peak Forward Gate Current	I <sub>GTM</sub>			8.0	Amp
Peak Reverse Gate Voltage	V <sub>GRM</sub>			5	Volts
Maximum Average Gate Power Dissipation	P <sub>GM (AVE)</sub>			60	Watts

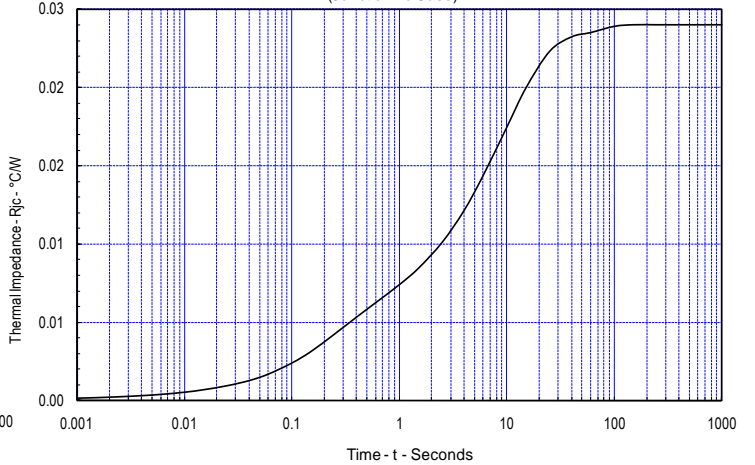
**Thermal Characteristics**

Characteristics	Symbol		Max.	Units
Thermal Resistance, Junction to Case	R <sub>ΘJ-C</sub>	Per Module, both conducting	0.024	°C/W
Thermal Impedance Coefficients	Z <sub>ΘJ-C</sub>	Z <sub>ΘJ-C</sub> = K <sub>1</sub> (1-exp(-t/τ <sub>1</sub> )) + K <sub>2</sub> (1-exp(-t/τ <sub>2</sub> )) + K <sub>3</sub> (1-exp(-t/τ <sub>3</sub> )) + K <sub>4</sub> (1-exp(-t/τ <sub>4</sub> ))	K <sub>1</sub> = 4.05 E-04 K <sub>2</sub> = 5.19 E-03 K <sub>3</sub> = 1.63 E-02 K <sub>4</sub> = 2.12 E-03	τ <sub>1</sub> = 6.24 E-03 τ <sub>2</sub> = 2.46 E-01 τ <sub>3</sub> = 8.20 τ <sub>4</sub> = 35.33
Thermal Resistance, Case to Sink Lubricated	R <sub>ΘC-S</sub>	Per Module	0.009	°C/W

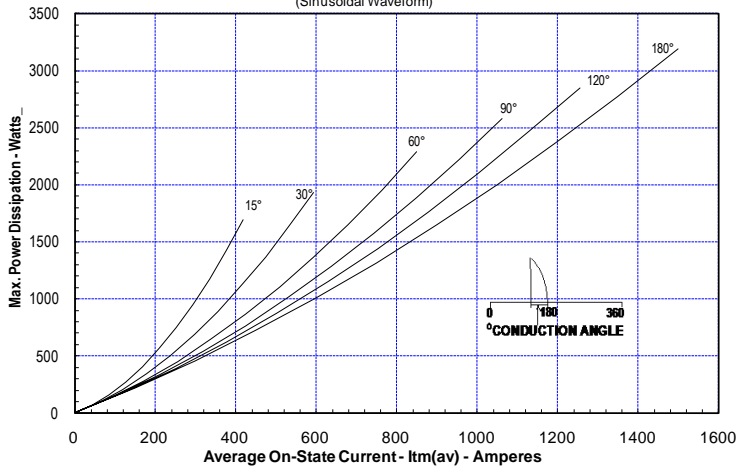
Maximum On-State Forward Voltage Drop  
(T<sub>j</sub> = 125°C)



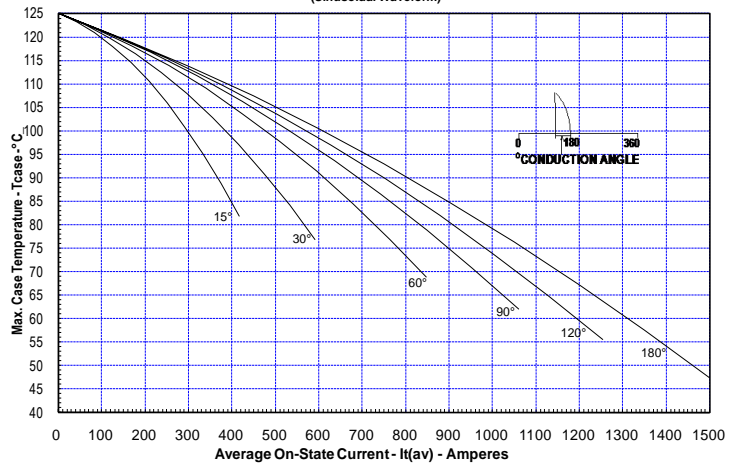
Maximum Transient Thermal Impedance  
(Junction To Case)



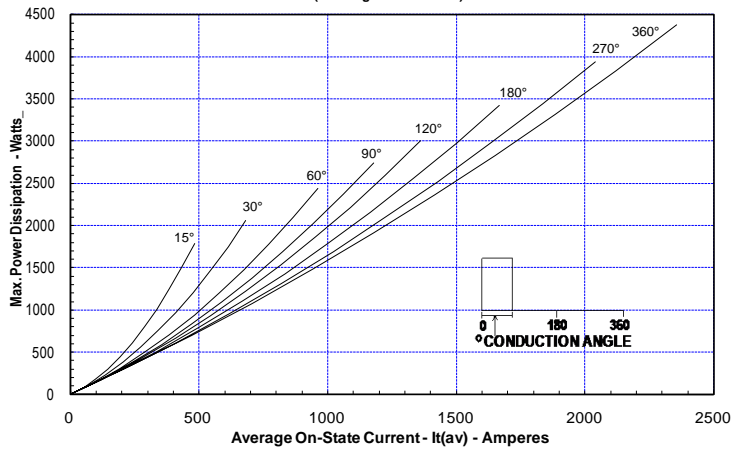
Maximum On-State Power Dissipation  
(Sinusoidal Waveform)



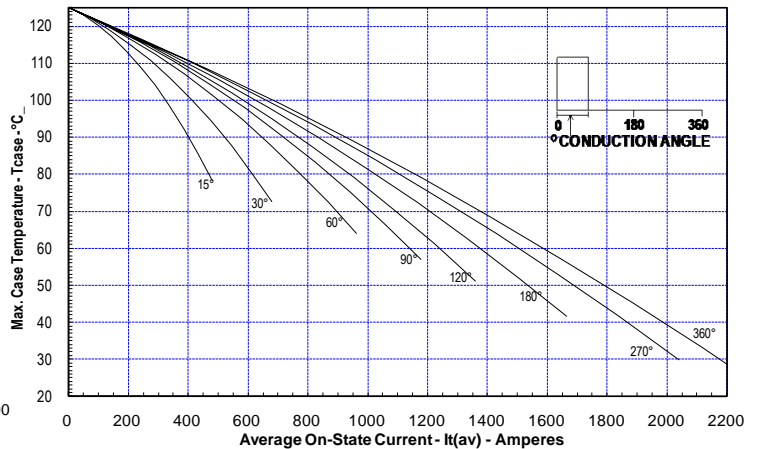
Maximum Allowable Case Temperature  
(Sinusoidal Waveform)



Maximum On-State Power Dissipation  
(Rectangular Waveform)



Maximum Allowable Case Temperature  
(Rectangular Waveform)



**POW-R-BLOK™**  
**Single SCR Isolated Module**  
**1000 Amperes / Up to 4000 Volts**

DIM.	INCHES	MILLIMETERS
A	7.80	198.1
B	4.00	101.6
C	2.68	68.1
D	6.44	163.6
E	3.44	87.4
F	.28	7.1
G	7.31	185.7
H	7.00	177.8
J	1.65	42
K	.21	5.3
L	.28	7.1
M	.281	7.1
N	.45	11.4
P	.54	13.7
O	5.93	150.6
R	.19	4.8
S	.11	2.8
T	.48	12.2
U	2.28	58
V	2.54	64.5
W	4.93	125.2
X	3.81	96.8
Y	.03	.8
Z	2.00	50.8
AA	1.00	25.4
BB	.50	12.7
CC	1.00	25.4
DD	.406	10.3
FF	.66	16.8

